

2.4 GHz High-Linearity, WLAN Front-End Module

FEATURES

- Input/output ports internally matched to 50 Ω and DC decoupled
- Package available
 - 16-contact X2QFN – 2.5mm x 2.5mm x 0.4mm
- All non-Pb (lead-free) devices are RoHS compliant

Transmitter Chain

- Gain:
 - Typically 24 dB gain
- Dynamic linear output power:
 - Meets 802.11g OFDM ACPR requirement up to 21 dBm using 3.6V V_{CC} and 22.5 dBm using 5V V_{CC}
 - 17 dBm using 3.6V, 18 dBm using 5.0V, at 3% EVM for 802.11g, 54 Mbps
 - 15 dBm using 3.6V, 16 dBm using 5.0V, at 1.75% dynamic EVM for 256 QAM, 40 MHz bandwidth
- Operating current
 - 150 mA @ $P_{OUT} = 17$ dBm for 802.11g, 3.6V
 - 130 mA @ $P_{OUT} = 15$ dBm for MCS9, 3.6V
- PA Control current, $I_{PEN} < 3$ mA
- Idle current, $I_{CO} : 90$ mA (3.6V V_{CC})
- Low shut-down current: ~ 2 μ A
- Power-up/down control
 - Turn on/off time (10%–90%) < 400 ns
- Limited variation over temperature
 - ~ 1 dB power variation between -40°C to $+85^{\circ}\text{C}$
- Linear on-chip power detection
 - Load and temperature insensitive
 - > 20 dB dynamic range on-chip power detection

Receiver Chain

- Gain: Typically 12 dB gain
- Noise figure: Typically 2.5 dB
- Receiver input P1dB: Typically -6 dBm
- LNA bypass loss: Typically 9 dB

Bluetooth[®] Chain

- Loss: 1.6dB
- Output P1dB: > 25 dBm

APPLICATIONS

- WLAN (IEEE 802.11b/g/n/256 QAM)
- Home RF
- Cordless phones
- 2.4 GHz ISM wireless equipment

1.0 PRODUCT DESCRIPTION

SST12LF09 is a 2.4 GHz Front-end Module (FEM) designed in compliance with IEEE 802.11b/g/n and 256 QAM applications. Based on GaAs pHEMT/HBT technology, it combines a high-performance transmitter power amplifier (PA), a low-noise receiver amplifier (LNA) and an antenna Tx/Rx/BT switch (SP3T SW). The input/output RF ports are single-ended and internally matched to 50 Ω . These RF ports are DC decoupled, and require no DC-blocking capacitors or matching components. This helps reduce the system board Bill of Materials (BOM) cost.

There are two components to the FEM: the Transmitter (TX) chain and the Receiver (RX) chain.

The TX chain includes a high-efficiency PA based on the InGaP/GaAs HBT technology. The transmitter is optimized for high linearity, 802.11n and 256 QAM operation—typically providing 15 dBm with 1.75% dynamic EVM for 256 QAM, 40 MHz operation and 17 dBm at 3% for 802.11g, 54 Mbps operation at 3.6V. At 5V V_{CC} , the transmitter provides typically 17 dBm with 1.75% dynamic EVM for 256 QAM, 40 MHz operation and 18 dBm at 3% for 802.11g, 54 Mbps operation.

SST12LF09 has a transmitter on-chip, single-ended power detector that is stable over temperature and insensitive to output VSWR. It features a wide dynamic-range (20 dB) with dB-wise linear operation. The on-chip power detector provides a reliable solution to board-level power control.

The Rx chain provides typically 12 dB gain with 2.5 dB noise figure. With the LNA bypassed, the receiver loss is typically 9 dB.

SST12LF09 is offered in a 16-contact X2QFN package. See [Figure 3-1](#) for pin assignments and [Table 4-1](#) for pin descriptions.

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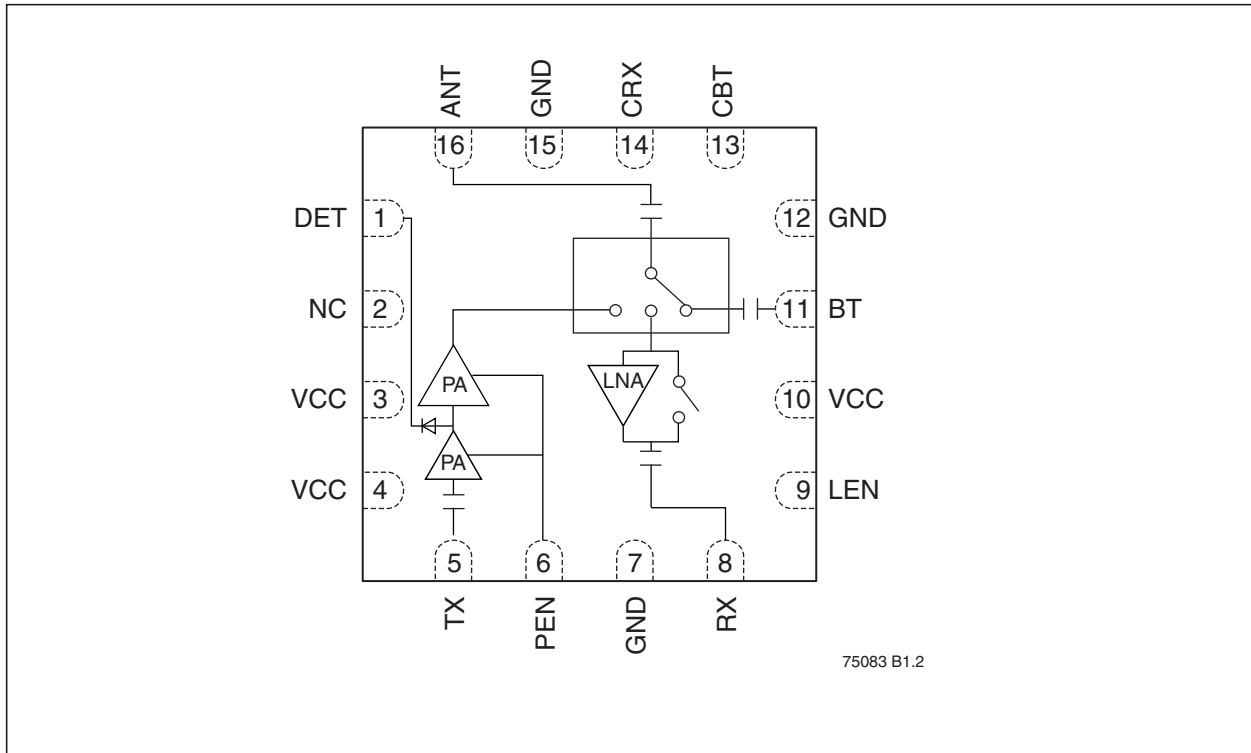
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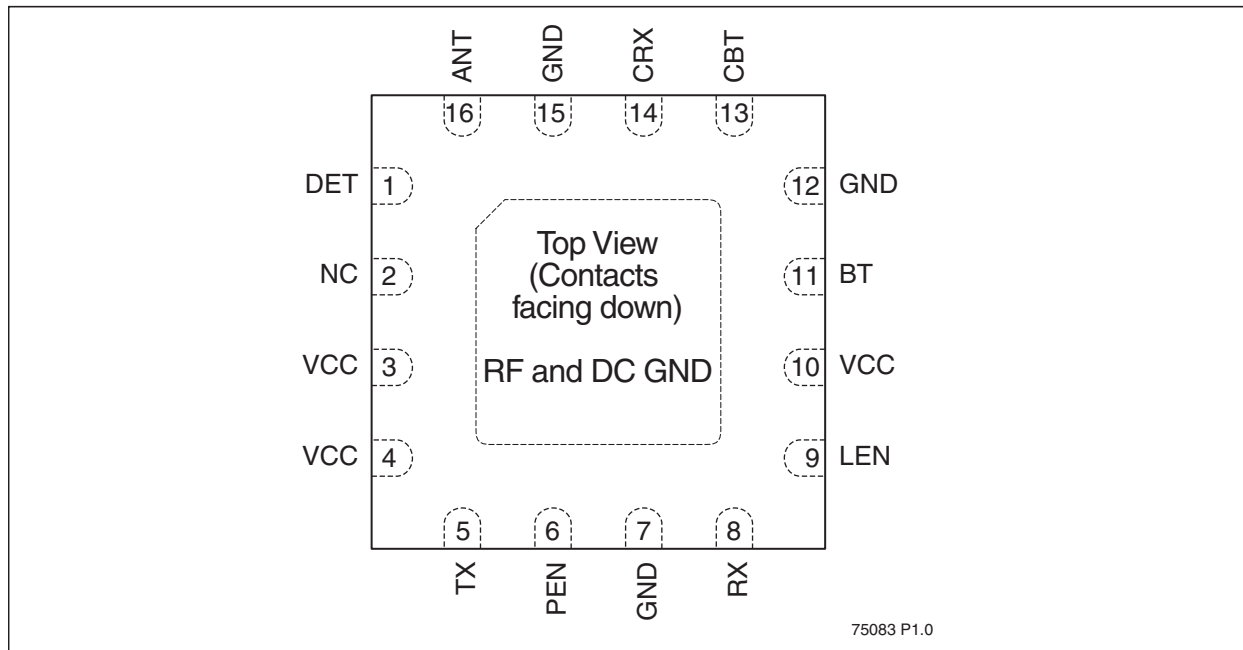
2.0 FUNCTIONAL BLOCKS

FIGURE 2-1: FUNCTIONAL BLOCK DIAGRAM



3.0 PIN ASSIGNMENTS

FIGURE 3-1: PIN ASSIGNMENTS FOR 16-CONTACT X2QFN



75083 P1.0

4.0 PIN DESCRIPTIONS

TABLE 4-1: PIN DESCRIPTION

| Symbol | Pin No. | Pin Name | Type ¹ | Function |
|--------|---------|--------------|-------------------|---------------------------------|
| DET | 1 | | O | Detector output voltage ground |
| NC | 2 | | | No connect |
| VCC | 3 | Power Supply | PWR | Supply voltage |
| VCC | 4 | Power Supply | PWR | Supply voltage |
| TX | 5 | | I | RF transmit input |
| PEN | 6 | | I | PA enable |
| GND | 7 | Ground | | Ground pad |
| RX | 8 | | O | Rx output |
| LEN | 9 | | I | LNA enable |
| VCC | 10 | | PWR | Supply voltage |
| BT | 11 | | I/O | Bluetooth RF port |
| GND | 12 | Ground | | Ground pad |
| CBT | 13 | | I | Bluetooth switch control |
| CRX | 14 | | I | Receiver switch control voltage |
| GND | 15 | Ground | | Ground Pad |
| ANT | 16 | | I/O | Antenna |

1. I=Input, O=Output

5.0 ELECTRICAL SPECIFICATIONS

The DC and RF specifications for the power amplifier are specified below. Refer to Table 5-2 for the DC voltage and current specifications.

Absolute Maximum Stress Ratings (Applied conditions greater than those listed under “Absolute Maximum Stress Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these conditions or conditions greater than those defined in the operational sections of this data sheet is not implied. Exposure to absolute maximum stress rating conditions may affect device reliability.)

| | |
|--|----------------------|
| Tx input power to pin 5 (TX) | +5 dBm |
| Rx input power to pin 16 (ANT with LNA ON) | +5 dBm |
| Average Tx output power from pin 16 (ANT) ¹ | +26 dBm |
| Supply Voltage at pins 3 and 4 (V_{CC}) | -0.3V to +5.5V |
| PA Enable Voltage to pin 6 (PEN) | -0.3V to +3.6V |
| DC supply current (I_{CC}) ² | 400 mA |
| Operating Temperature (T_A) | -40°C to +85°C |
| Storage Temperature (T_{STG}) | -40°C to +120°C |
| Maximum Junction Temperature (T_J) | +150°C |
| Surface Mount Solder Reflow Temperature | 260°C for 10 seconds |

1. Never measure with CW source. Pulsed single-tone source with <50% duty cycle is recommended. Exceeding the maximum rating of average output power could cause permanent damage to the device.
2. Measured with 100% duty cycle 54 Mbps 802.11g OFDM Signal

TABLE 5-1: OPERATING RANGE

| Range | Ambient Temp | V_{CC} |
|----------|----------------|----------|
| Extended | -40°C to +85°C | 3.0-5.0V |

TABLE 5-2: DC ELECTRICAL CHARACTERISTICS AT 25°C FOR TX CHAIN

| Symbol | Parameter | Min. | Typ | Max. | Unit |
|-----------|---|------|------|------|------|
| V_{CC} | Supply Voltage, V_{CC} | 3.0 | 3.6 | 5.0 | V |
| I_{CQ} | Tx Idle current for $V_{CC} = 3.6V$ | | 90 | | mA |
| | Tx Idle current for $V_{CC} = 5.0V$ | | 95 | | mA |
| V_{PEN} | Tx Enable Voltage | 3.05 | 3.10 | 3.15 | V |
| I_{CC} | Tx Supply Current for 11g OFDM 54 Mbps signal: $P_{OUT} = 17$ dBm at $V_{CC} = 3.6V$ | | 150 | | mA |
| | $P_{OUT} = 18$ dBm at $V_{CC} = 5.0V$ | | 160 | | mA |
| I_{DD} | Rx Supply Current (with LNA ON) | | 9 | | mA |

TABLE 5-3: TX CHAIN RF CHARACTERISTICS AT $V_{CC} = 3.6V$, PEN=3.1V, 25°C

| Symbol | Parameter | Min. | Typ | Max. | Unit |
|------------------|---|------|-----|------|-------------|
| F _{L-U} | Frequency range | 2.4 | | 2.5 | GHz |
| Linearity, | Output Power with <3% EVM, 802.11g @ 54 Mbps OFDM | | 17 | | dBm |
| | Output Power level 1.75% Dynamic EVM, 256 QAM, 40 MHz | | 15 | | dBm |
| | Output Power level 2.5% Dynamic EVM, 802.11n, HT40 | | 16 | | dBm |
| | Spectrum Mask compliance, IEEE802.11b | | 21 | | dBm |
| G | Gain | 22 | 24 | | dB |
| RL _{IN} | Input return loss at TX port | | 14 | | dB |
| V _{DET} | Power detector output voltage at P _{OUT} =5 dBm, IEEE802.11g | 0.25 | | 0.35 | V |
| | Power detector output voltage at P _{OUT} = 20 dBm, | 0.55 | | 0.65 | V |
| 2f, 3f, 4f, 5f | Harmonics at 17 dBm | | | -30 | dBm/ MHz |

TABLE 5-4: TX CHAIN RF CHARACTERISTICS AT $V_{CC} = 5.0V$, PEN=3.1V, 25°C

| Symbol | Parameter | Min. | Typ | Max. | Unit |
|------------------|---|------|-----|------|-------------|
| F _{L-U} | Frequency range | 2.4 | | 2.5 | GHz |
| Linearity, | Output Power with <3% EVM, 802.11g @ 54 Mbps OFDM | | 18 | | dBm |
| | Output Power level 1.75% Dynamic EVM, 256 QAM, 40 MHz | | 16 | | dBm |
| | Output Power level 2.5% Dynamic EVM, 802.11n, HT40 | | 17 | | dBm |
| | Spectrum Mask compliance, IEEE802.11b | | 22 | | dBm |
| G | Gain | 22 | 24 | | dB |
| RL _{IN} | Input return loss at TX port | | 14 | | dB |
| V _{DET} | Power detector output voltage at P _{OUT} =5 dBm, IEEE802.11g | 0.25 | | 0.35 | V |
| V _{DET} | Power detector output voltage at P _{OUT} = 20 dBm, | 0.55 | | 0.65 | V |
| 2f, 3f, 4f, 5f | Harmonics at 17 dBm | | | -30 | dBm/ MHz |

TABLE 5-5: RX CHAIN RF CHARACTERISTICS AT $V_{CC} = 3.6V-5V$, LEN=3.1V, CRX = 3.1V, 25°C

| Symbol | Parameter | Min. | Typ | Max. | Unit |
|------------------|--|------|-----|------|------|
| F _{L-U} | Frequency range | 2.4 | | 2.5 | GHz |
| G | Gain, with LNA ON | | 12 | | dB |
| NF | Noise figure, with LNA ON | | 2.5 | | dB |
| IP1dB | Input P1dB, with LNA ON | | -6 | | dBm |
| Loss | LNA bypass loss | | 9 | | dB |
| RL _{IN} | Input return loss at Antenna port with LNA | | 12 | | dB |

TABLE 5-6: BLUETOOTH CHAIN RF CHARACTERISTICS AT $V_{CC} = 3.6V-5V$, CBT=3.1V, 25°C

| Symbol | Parameter | Min. | Typ | Max. | Unit |
|------------------|-----------------|------|-----|------|------|
| F _{L-U} | Frequency range | 2.4 | | 2.5 | GHz |
| L | Loss | | 1.6 | | dB |
| RL | Return Loss | | 8 | | dB |

TABLE 5-7: CONTROL VOLTAGES¹

| Function | PEN | CRX | LEN | CBT |
|--------------------------|------|-----|-----|-----|
| Transmit mode | 3.1V | 0 | 0 | 0 |
| Bluetooth | 0 | 0 | 0 | 3V |
| Receive mode, LNA on | 0 | 3V | 3V | 0 |
| Receive mode, LNA bypass | 0 | 3V | 0 | 0 |
| OFF | 0 | 0 | 0 | 0 |

1. No other operating modes are allowed

6.0 TYPICAL PERFORMANCE CHARACTERISTICS

6.1 Transmitter

Test Conditions: $V_{CC} = 3.6V$, $PEN = 3.10V$, $LEN = 0V$, $CRX = 0V$, $CBT = 0V$, $T_A = 25^\circ C$, unless otherwise specified

FIGURE 6-1: S-PARAMETERS

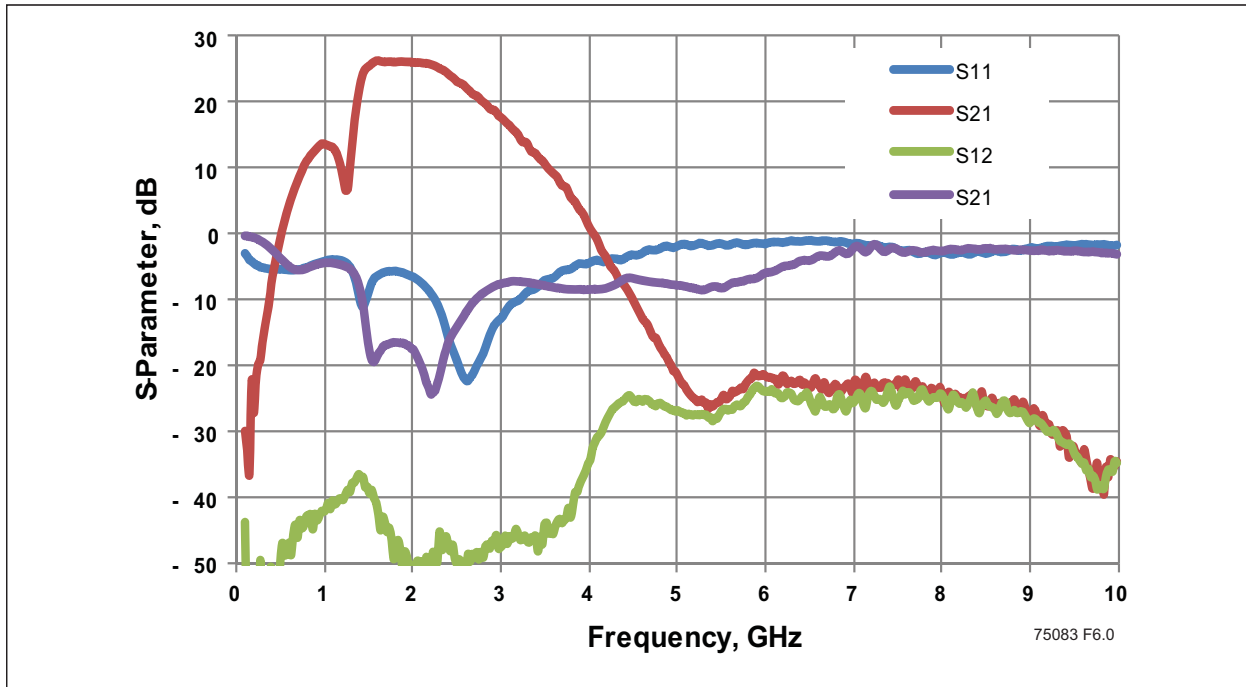


FIGURE 6-2: TRANSMITTER EVM VERSUS OUTPUT POWER MEASURED USING 802.11G WITH EQUALIZER TRAINING USING SEQUENCE ONLY

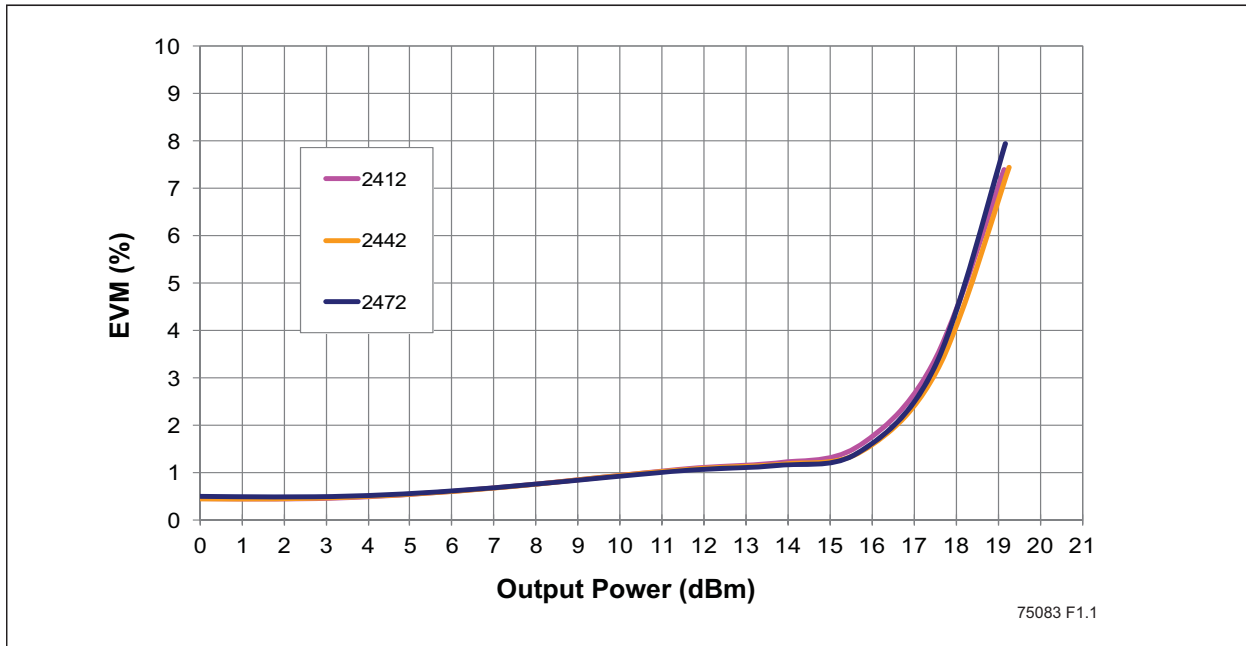


FIGURE 6-3: TRANSMITTER DYNAMIC EVM VERSUS OUTPUT POWER MEASURED USING 256 QAM, 40 MHZ BANDWIDTH WITH EQUALIZER TRAINING USING SEQUENCE ONLY

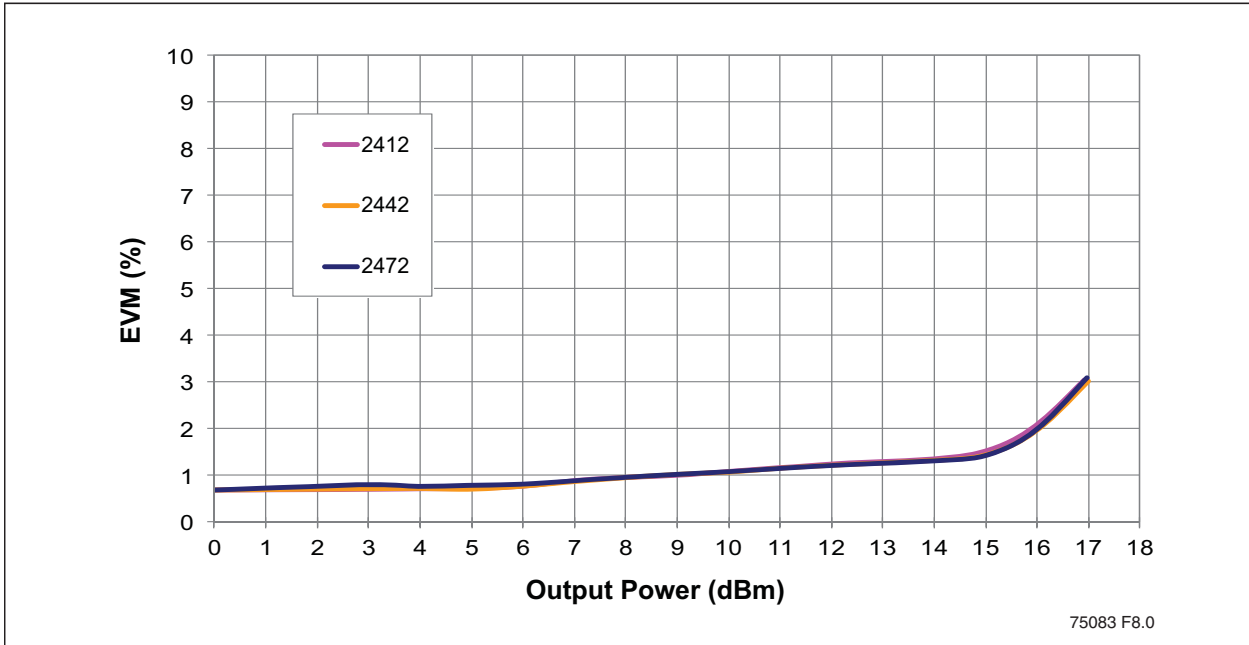


FIGURE 6-4: GAIN VERSUS OUTPUT POWER

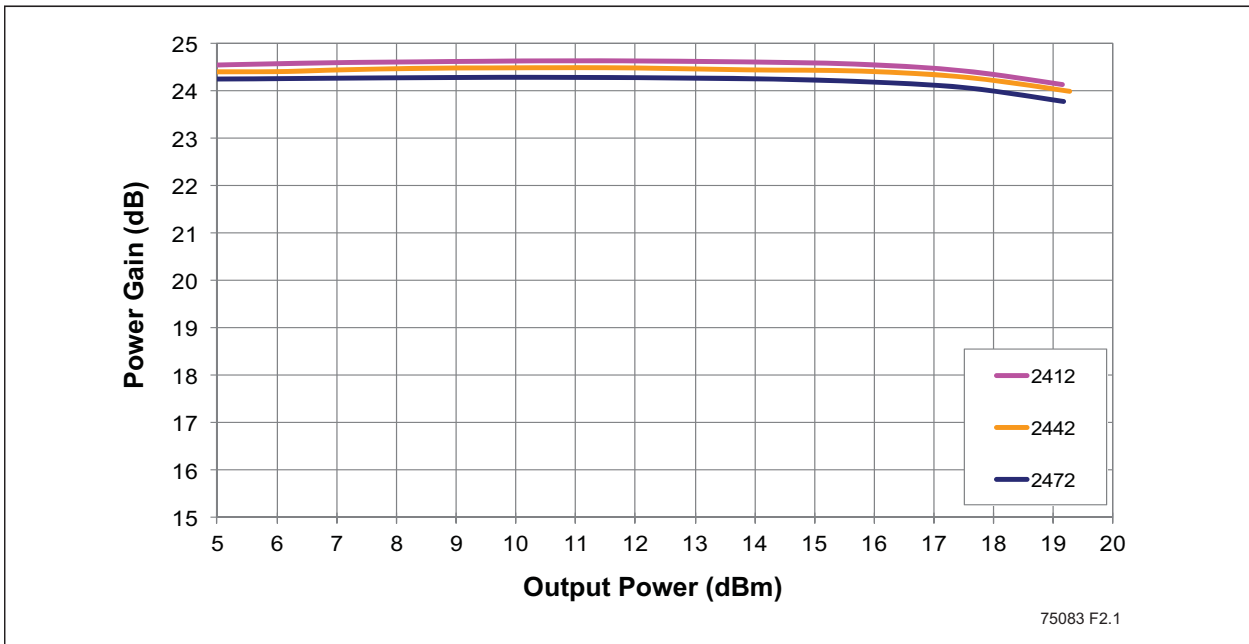


FIGURE 6-5: TRANSMITTER DC CURRENT VERSUS OUTPUT POWER

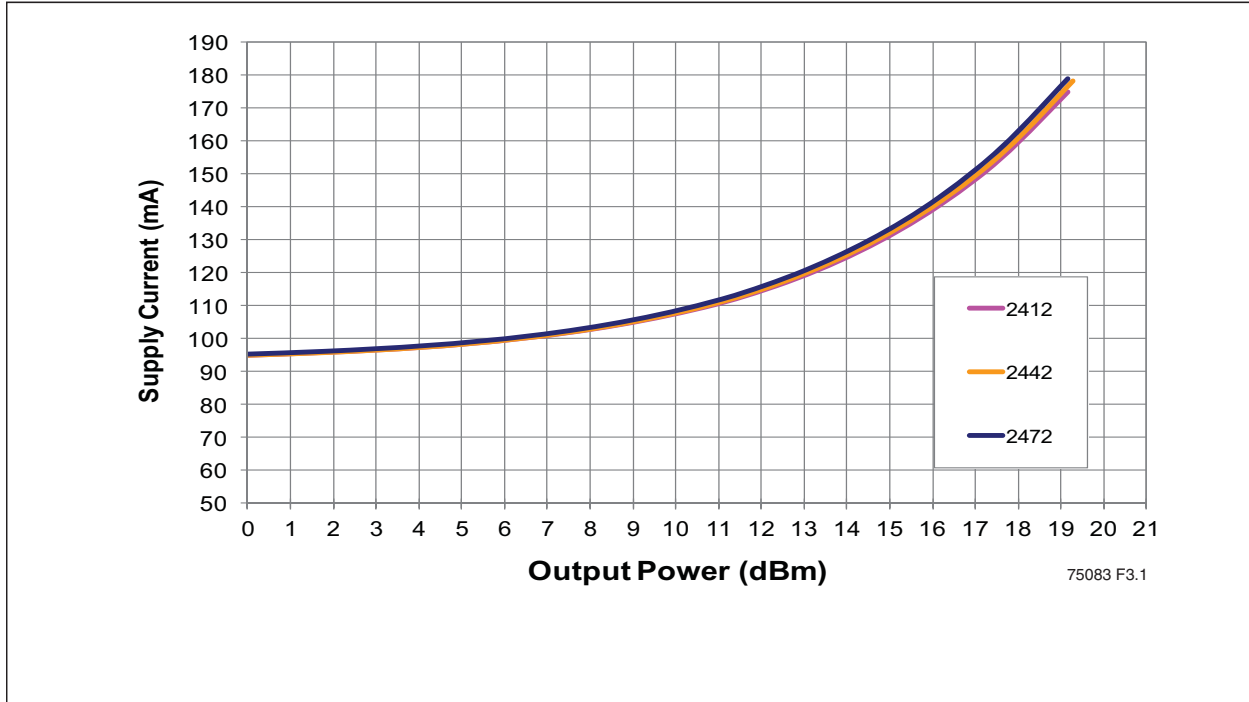
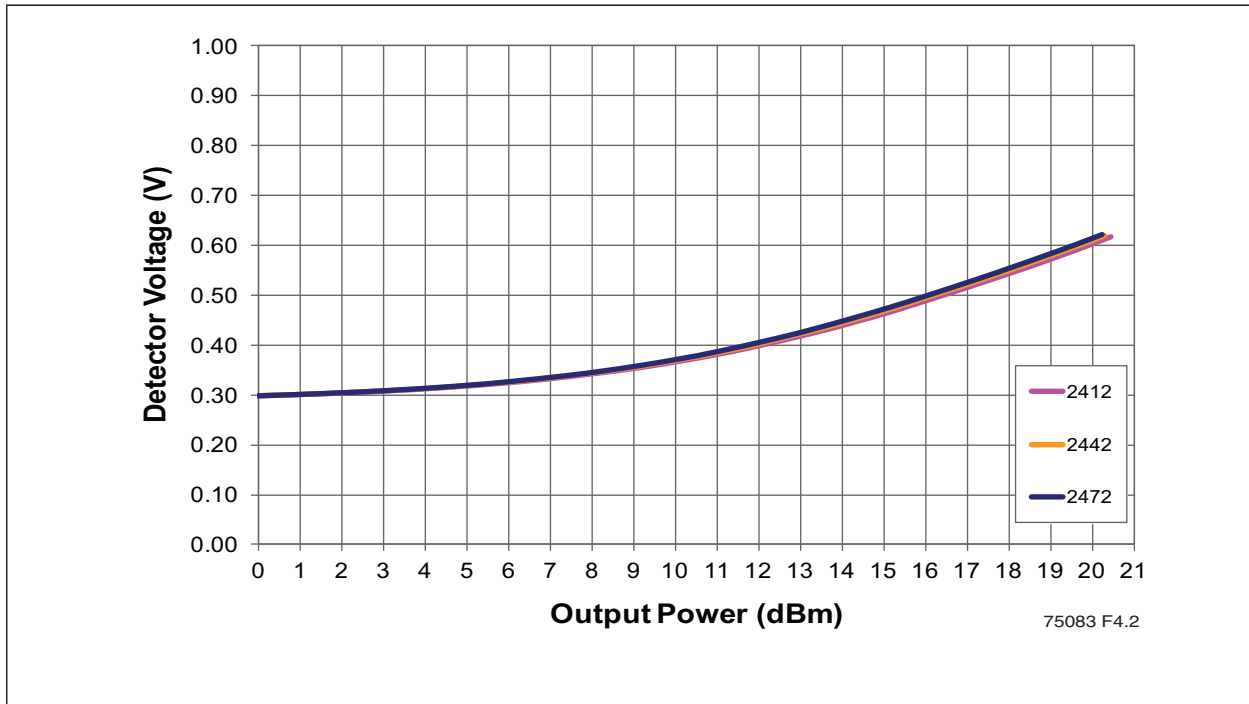


FIGURE 6-6: DETECTOR VOLTAGE VERSUS OUTPUT POWER



6.2 Receiver

Test Conditions: $V_{CC} = 3.6V$, $LEN = 3.3V$, $CRX = 3.3V$, $PEN = 0V$, $CBT = 0V$,
 $T_A = 25^\circ C$, unless otherwise specified

FIGURE 6-7: RECEIVER S-PARAMETER

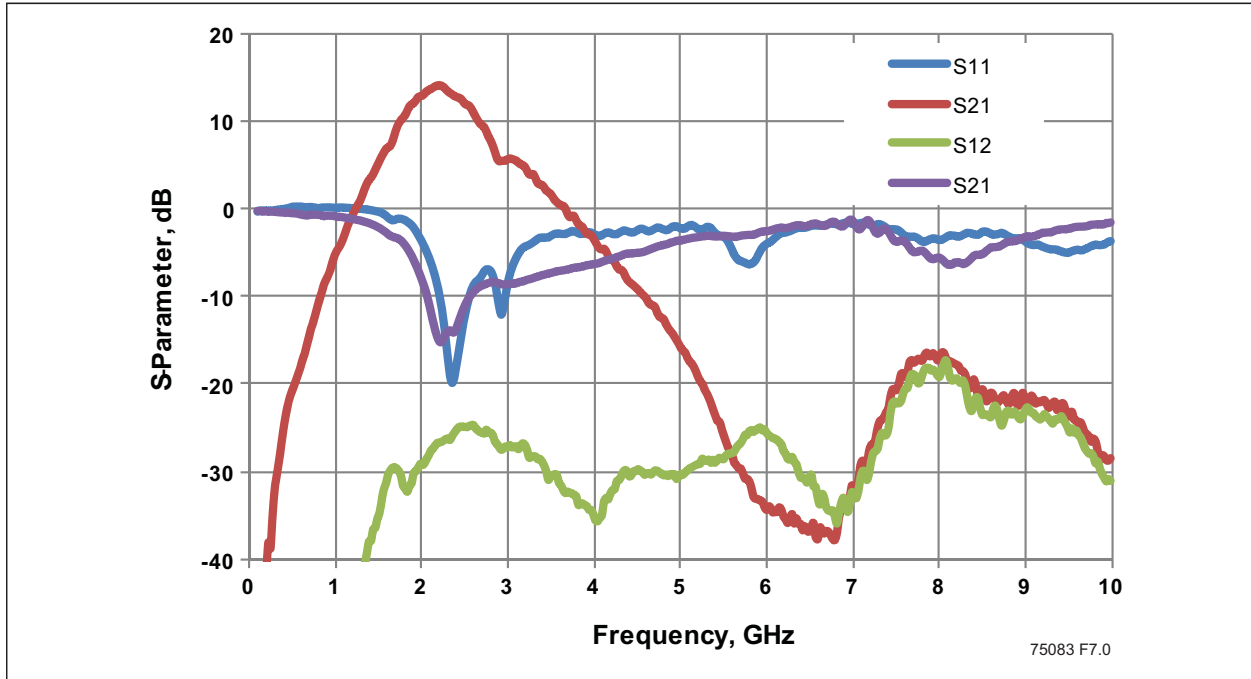


FIGURE 6-8: RECEIVER NOISE FIGURE

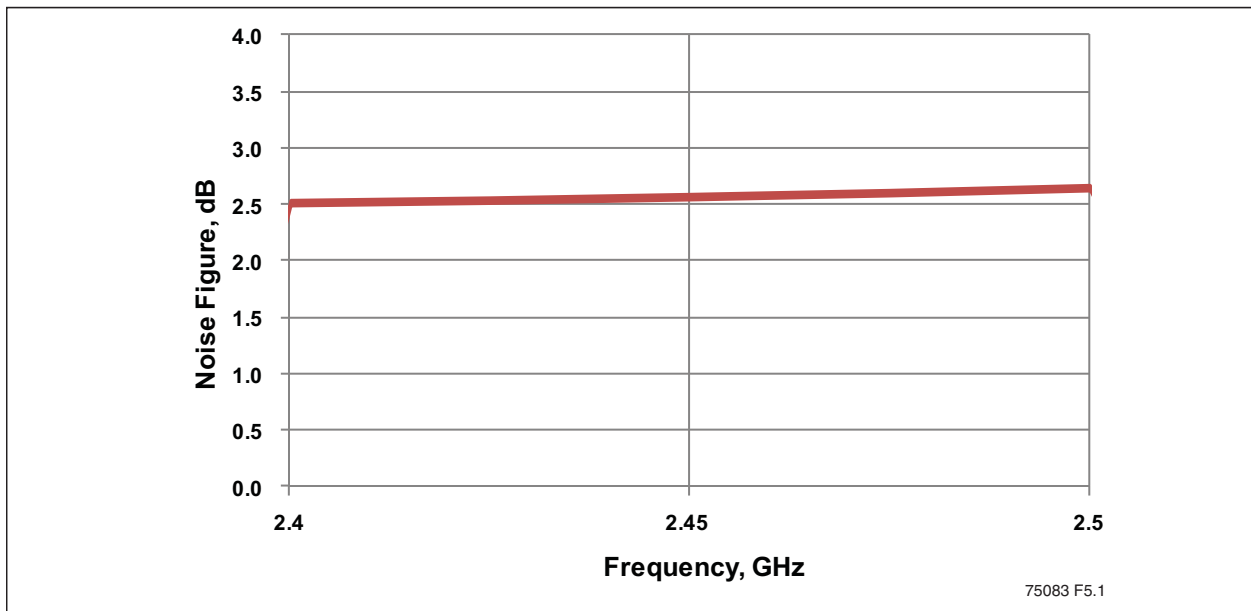
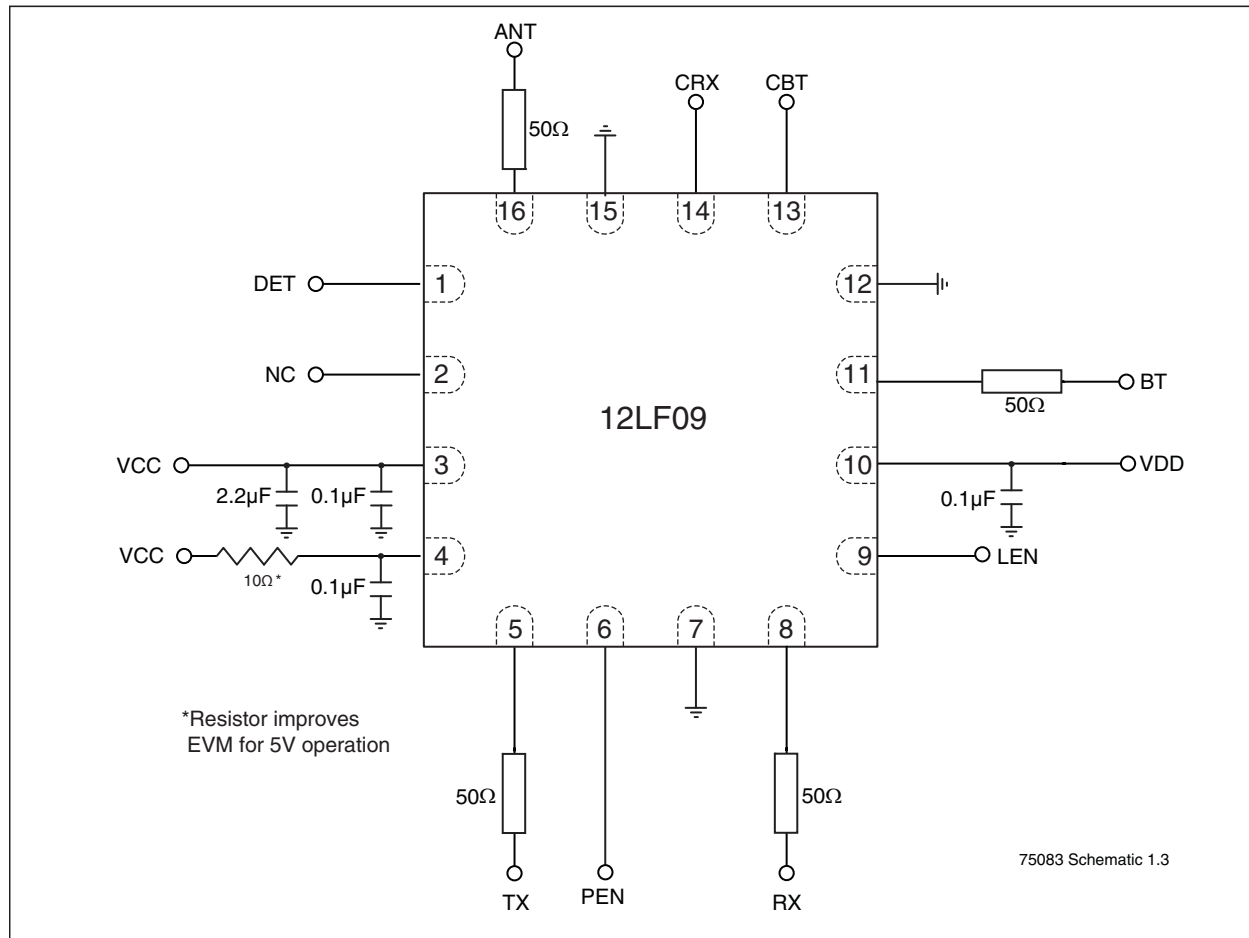


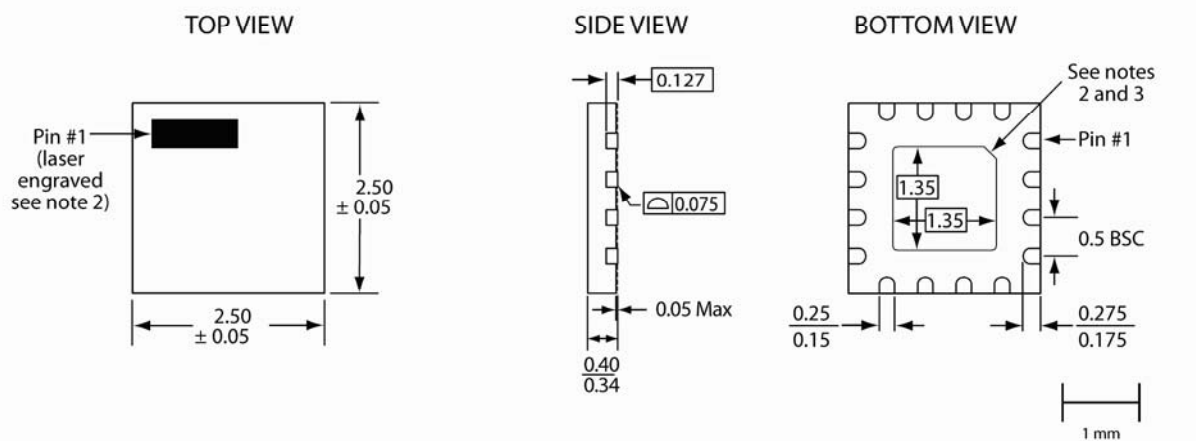
FIGURE 6-9: TYPICAL SCHEMATIC



7.0 PACKAGING DIAGRAMS

16-Lead Super-Thin Quad Flatpack No-Leads (Q3CE/F) - 2.5x2.5 mm Body [X2QFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Note:

1. From the bottom view, the pin #1 indicator may be either a 45-degree chamfer or a half-circle notch.
2. The topside pin #1 indicator is laser engraved; its approximate shape and location is as shown.
3. The external paddle is electrically connected to the die back-side and to VSS.
This paddle must be soldered to the PC board; it is required to connect this paddle to the VSS of the unit.
Connection of this paddle to any other voltage potential will result in shorts and electrical malfunction of the device.
4. Untoleranced dimensions are nominal target dimensions.
5. All linear dimensions are in millimeters (max/min).

TABLE 7-1: REVISION HISTORY

| Revision | Description | Date |
|-----------------|---|-------------|
| A | <ul style="list-style-type: none">• Initial release of data sheet | May 2013 |
| B | <ul style="list-style-type: none">• Revised “Features” on page 1• Updated Tables 5-2, 5-3, 5-5, 5-6• Updated Figure 6-6 on page 10 and Figure 6-9 on page 12• Changed V_{DD} to V_{CC} throughout• Updated Figure 2-1 on page 3 | Dec 2013 |

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| <u>PART NO.</u> | <u>XXX</u> | |
|---------------------|------------|---|
| Device | Package | |
| Device: SST12LF09 | | = 2.4 GHz High-Gain, High-Efficiency Front-end Module |
| Package: Q3CE | | = X2QFN (2.5mm x 2.5mm), 0.4 max thickness 16-contact |
| Evaluation Kit Flag | K | = Evaluation Kit |

Valid Combinations:
SST12LF09-Q3CE
SST12LF09-Q3CE-K

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